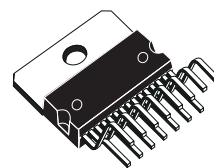


**11W+11W AMPLIFIER WITH DC VOLUME CONTROL**

- 11+11W OUTPUT POWER  
R<sub>L</sub> = 8Ω @THD = 10% V<sub>CC</sub> = 28V
- ST-BY AND MUTE FUNCTIONS
- LOW TURN-ON TURN-OFF POP NOISE
- LINEAR VOLUME CONTROL DC COUPLED WITH POWER OP. AMP.
- NO BOUCHEROT CELL
- NO ST-BY RC INPUT NETWORK
- SINGLE SUPPLY RANGING UP TO 35V
- SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION
- INTERNALLY FIXED GAIN
- SOFT CLIPPING
- VARIABLE OUTPUT AFTER VOLUME CONTROL CIRCUIT
- MULTIWATT 15 PACKAGE

**MULTIPOWER BI50II TECHNOLOGY**



**Multiwatt15**

**ORDERING NUMBER: TDA7495**

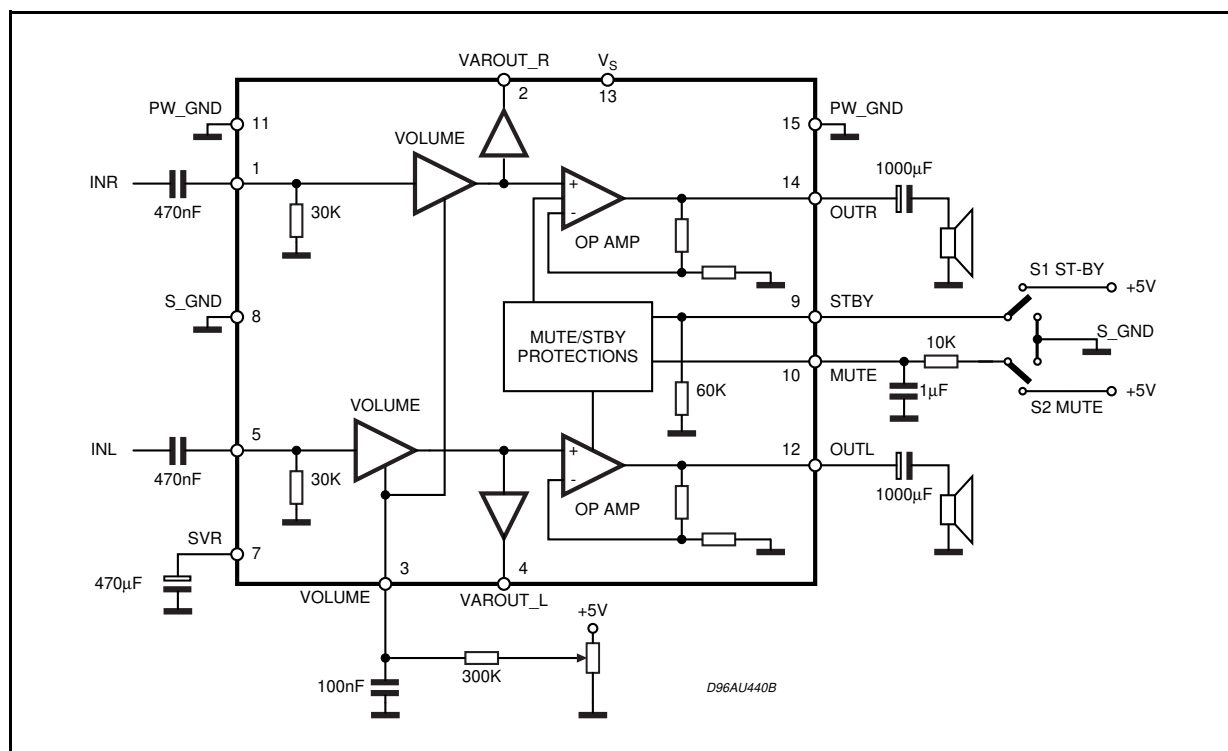
power amplifier assembled in the @ Multiwatt 15 package, specially designed for high quality sound, TV applications.

Features of the TDA7495 include linear volume control, Stand-by and mute functions.

**DESCRIPTION**

The TDA7495 is a stereo 11+11W class AB

**BLOCK AND APPLICATION DIAGRAM**



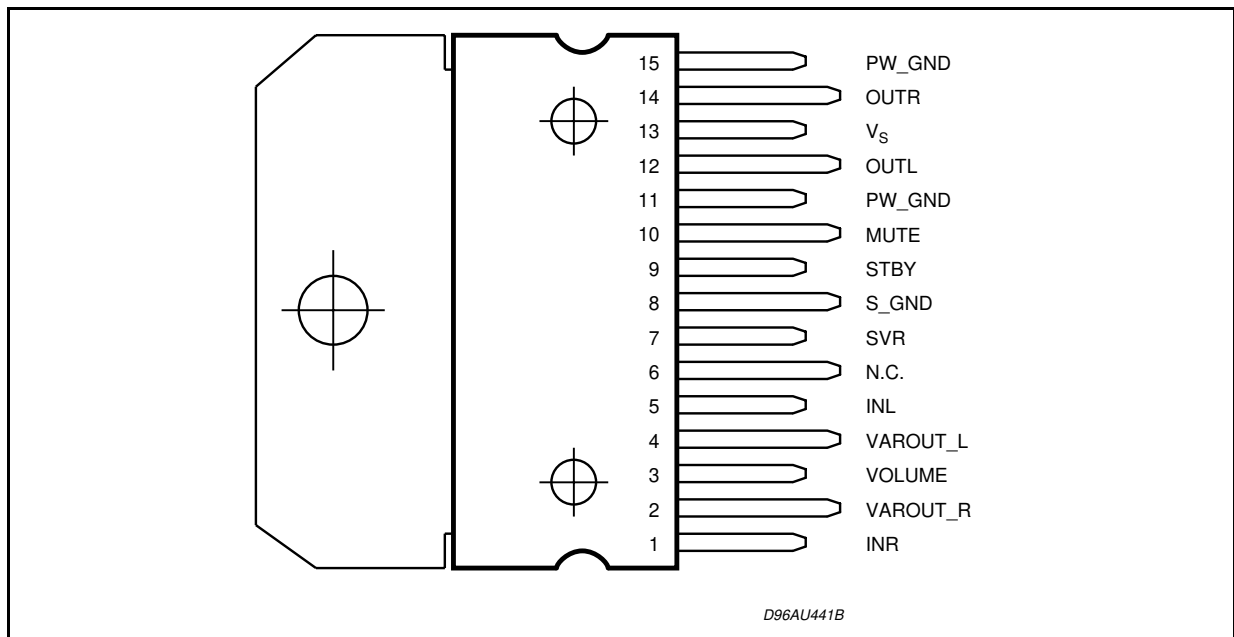
# TDA7495

## ABSOLUTE MAXIMUM RATINGS

| Symbol         | Parameter  | Value      | Unit             |
|----------------|--|------------|------------------|
| $V_S$          | DC Supply Voltage  | 35         | V                |
| $V_{IN}$       | Maximum Input Voltage                                    | 8          | V <sub>pp</sub>  |
| $P_{tot}$      | Total Power Dissipation ( $T_{amb} = 70^\circ\text{C}$ ) | 20         | W                |
| $T_{amb}$      | Ambient Operating Temperature (1)                        | -20 to 85  | $^\circ\text{C}$ |
| $T_{stg}, T_j$ | Storage and Junction Temperature                         | -40 to 150 | $^\circ\text{C}$ |
| $V_3$          | Volume CTRL DC voltage                                   | 7          | V                |

(1) Operation between -20 to 85  $^\circ\text{C}$  guaranteed by correlation with 0 to 70 $^\circ\text{C}$ .

## PIN CONNECTION (Top view)



## THERMAL DATA

| Symbol           | Parameter                           | Value                  | Unit                      |
|------------------|-------------------------------------|------------------------|---------------------------|
| $R_{th\ j-case}$ | Thermal Resistance Junction-case    | Typ. = 2    Max. = 2.8 | $^\circ\text{C}/\text{W}$ |
| $R_{th\ j-amb}$  | Thermal Resistance Junction-ambient | max 35                 | $^\circ\text{C}/\text{W}$ |

**ELECTRICAL CHARACTERISTICS** (Refer to the test circuit  $V_S = 20\text{V}$ ;  $R_L = 8\Omega$ ,  $R_G = 50\Omega$ ,  $T_{amb} = 25^\circ\text{C}$ ).

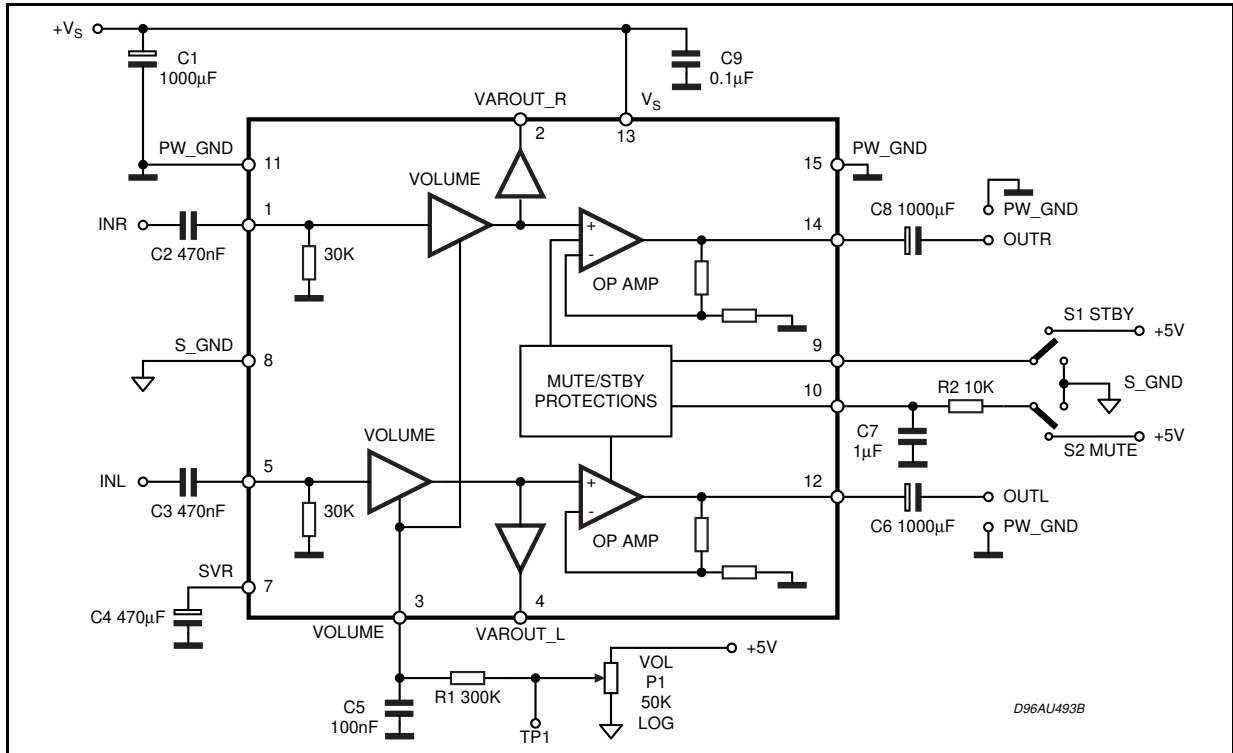
| Symbol            | Parameter                                  | Test Condition                                     | Min. | Typ. | Max. | Unit |
|-------------------|--|--|------|------|------|------|
| $V_S$             | Supply Voltage Range                       |  | 11   |      | 35   | V    |
| $I_q$             | Total Quiescent Current                    |  |      | 70   | 100  | mA   |
| DCV <sub>os</sub> | Output DC Offset Referred to SVR Potential | No Input Signal                                    | -650 |      | 650  | mV   |
| $V_o$             | Quiescent Output Voltage                   |  |      | 10   |      | V    |
| $P_o$             | Output Power                               | THD = 10%; $R_L = 8\Omega$ ; $V_S = 28\text{V}$    | 9.5  | 11   |      | W    |
|                   |  | THD = 1%; $R_L = 8\Omega$ ; $V_S = 28\text{V}$     | 7.5  | 8    |      | W    |
|                   |  | THD = 10%; $R_L = 4\Omega$ ; $V_{CC} = 20\text{V}$ | 7    | 8    |      | W    |
|                   |  | THD = 1%; $R_L = 4\Omega$ ; $V_{CC} = 20\text{V}$  | 5    | 6    |      | W    |
|                   |  | THD = 10%; $R_L = 8\Omega$ ; $V_{CC} = 18\text{V}$ | 3.5  | 3.8  |      | W    |
|                   |  | THD = 1%; $R_L = 8\Omega$ ; $V_{CC} = 18\text{V}$  | 2.6  | 2.9  |      | W    |

## ELECTRICAL CHARACTERISTICS (continued)

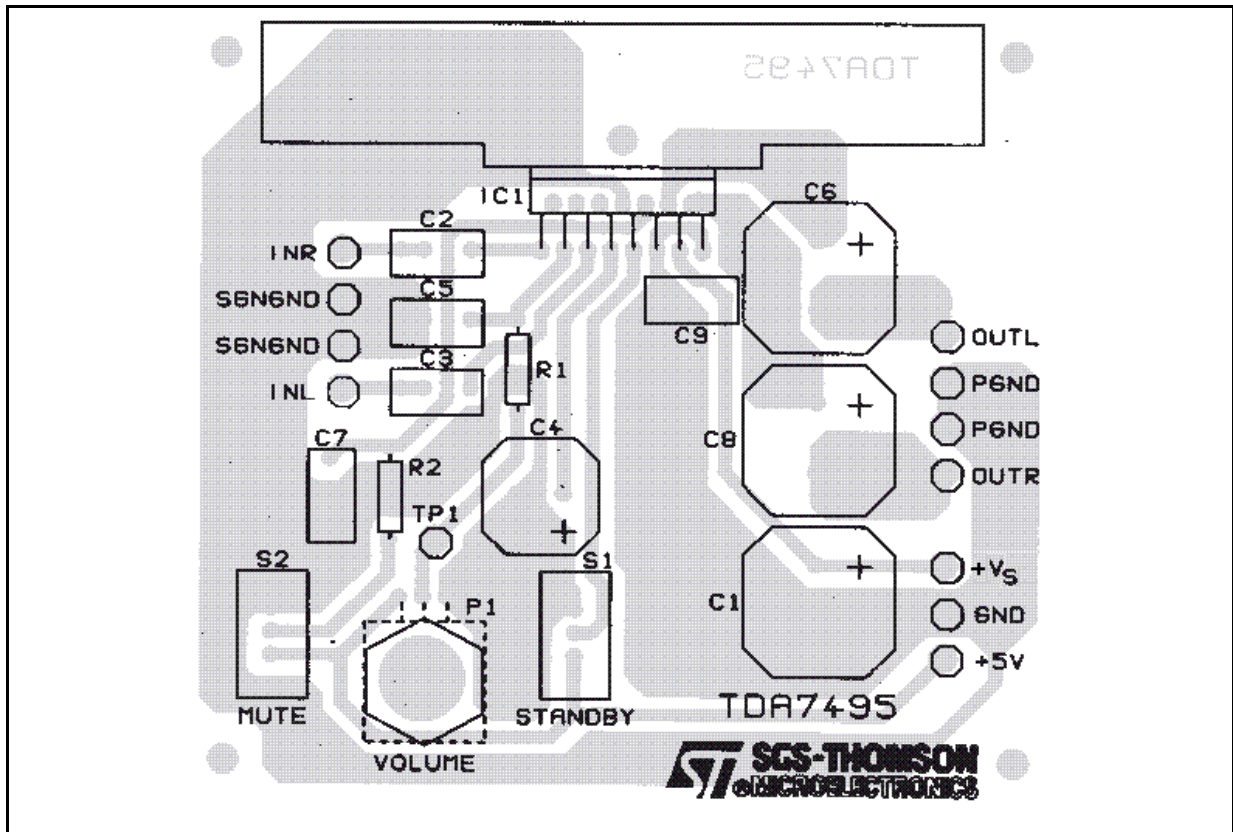
| Symbol   | Parameter                     | Test Condition   | Min. | Typ. | Max. | Unit                           |
|--|-------------------------------|--|------|------|------|--------------------------------|
| THD  | Total Harmonic Distortion     | $G_V = 30\text{dB}$ ; $P_O = 1\text{W}$ ; $f = 1\text{KHz}$ ;  |      |      | 0.4  | %                              |
| $I_{\text{peak}}$                                    | Output Peak Current           | (internally limited)   | 1.7  | 2.4  |      | A                              |
| $V_{\text{in}}$                                      | Input Signal                  |  |      |      | 2.8  | V <sub>rms</sub>               |
| $G_V$  | Closed Loop Gain              | Vol Ctrl > 4.5V  | 28.5 | 30   | 31.5 | dB                             |
| $G_{V\text{Line}}$                                   | Monitor Out Gain              | Vol Ctrl > 4.5V; $Z_{\text{load}} > 30\text{K}\Omega$  | -1.5 | 0    | 1.5  | dB                             |
| $A_{\text{Min VOL}}$                                 | Attenuation at Minimum Volume | Vol Ctrl < 0.5V  | 80   |      |      | dB                             |
| BW   |                               |  |      | 0.6  |      | MHz                            |
| $e_n$  | Total Output Noise            | $f = 20\text{Hz to } 22\text{KHz}$<br>Play, max volume   |      | 500  | 800  | $\mu\text{V}$                  |
|  |                               | $f = 20\text{Hz to } 22\text{KHz}$<br>Play, max attenuation  |      | 100  | 250  | $\mu\text{V}$                  |
|  |                               | $f = 20\text{Hz to } 22\text{KHz}$<br>Mute   |      | 60   | 150  | $\mu\text{V}$                  |
| SR   | Slew Rate                     |  | 5    | 8    |      | V/ $\mu\text{s}$               |
| $R_i$  | Input Resistance              |  | 22.5 | 30   |      | $\text{K}\Omega$               |
| $R_{\text{Var Out}}$                                 | Variable Output Resistance    |  |      | 30   | 100  | $\Omega$                       |
| $R_{\text{load Var Out}}$                            | Variable Output Load          |  | 2    |      |      | $\text{K}\Omega$               |
| SVR  | Supply Voltage Rejection      | $f = 1\text{kHz}$ ; max volume<br>$C_{\text{SVR}} = 470\mu\text{F}$ ; $V_{\text{RIP}} = 1\text{V}_{\text{rms}}$      | 35   | 39   |      | dB                             |
|  |                               | $f = 1\text{kHz}$ ; max attenuation<br>$C_{\text{SVR}} = 470\mu\text{F}$ ; $V_{\text{RIP}} = 1\text{V}_{\text{rms}}$ | 55   | 65   |      | dB                             |
| $T_M$  | Thermal Muting                |  |      | 150  |      | $^{\circ}\text{C}$             |
| $T_s$  | Thermal Shut-down             |  |      | 160  |      | $^{\circ}\text{C}$             |
| <b>MUTE STAND-BY &amp; INPUT SELECTION FUNCTIONS</b> |                               |  |      |      |      |                                |
| $V_{\text{ST-BY}}$                                   | Stand-by threshold            |  | 2.3  | 2.5  | 2.7  | V                              |
| $V_{\text{MUTE}}$                                    | Mute Threshold                |  | 2.3  | 2.5  | 2.7  | V                              |
| $I_{\text{qST-BY}}$                                  | Quiescent Current @ Stand-by  |  |      | 0.6  | 1    | mA                             |
| $A_{\text{MUTE}}$                                    | Mute Attenuation              |  | 50   | 65   |      | dB                             |
| $I_{\text{stbyBIAS}}$                                | Stand-by bias current         | Stand by on $V_{\text{ST-BY}} = 5\text{V}$<br>$V_{\text{MUTE}} = 5\text{V}$  |      | 80   |      | $\mu\text{A}$<br>$\mu\text{A}$ |
|  |                               | Play or Mute   | -20  | -5   |      | $\mu\text{A}$                  |
| $I_{\text{muteBIAS}}$                                | Mute bias current             | Mute   |      | 1    | 5    | $\mu\text{A}$                  |
|  |                               | Play   |      | 0.2  | 2    | $\mu\text{A}$                  |

**TDA7495**

**Figure 1a: Application Circuit.**



**Figure 1b: P.C.B. and Component Layout.**



### APPLICATION SUGGESTIONS

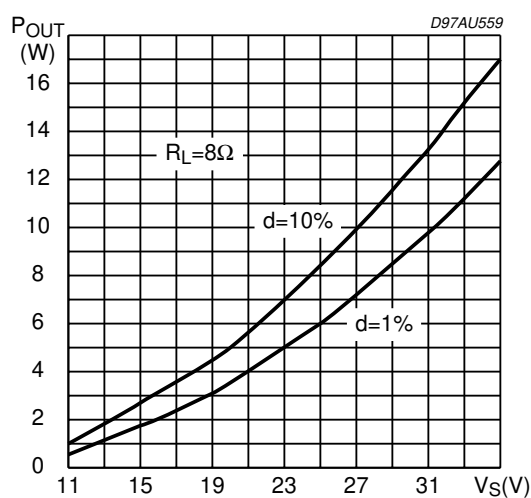
The recommended values of the external components are those shown on the application circuit of figure 1a. Different values can be used, the following table can help the designer.

| COMPONENT | SUGGESTION VALUE | PURPOSE                      | LARGER THAN SUGGESTION        | SMALLER THAN SUGGESTION        |
|-----------|------------------|------------------------------|-------------------------------|--------------------------------|
| R1        | 300K             | Volume control circuit       | Larger volume regulation time | Smaller volume regulation time |
| R2        | 10K              | Mute time constant           | Larger mute on/off time       | Smaller mute on/off time       |
| P1        | 50K              | Volume control circuit       |                               |                                |
| C1        | 1000 $\mu$ F     | Supply voltage bypass        |                               | Danger of oscillation          |
| C2        | 470nF            | Input DC decoupling          | Lower low frequency cutoff    | Higher low frequency cutoff    |
| C3        | 470nF            | Input DC decoupling          | Lower low frequency cutoff    | Higher low frequency cutoff    |
| C4        | 470 $\mu$ F      | Ripple rejection             | Better SVR                    | Worse SVR                      |
| C5        | 100nF            | Volume control time constant | Larger volume regulation time | Smaller volume regulation time |
| C6        | 1000 $\mu$ F     | Output DC decoupling         | Lower low frequency cutoff    | Higher low frequency cutoff    |
| C7        | 1 $\mu$ F        | Mute time constant           | Larger mute on/off time       | Smaller mute on/off time       |
| C8        | 1000 $\mu$ F     | Output DC decoupling         | Lower low frequency cutoff    | Higher low frequency cutoff    |
| C9        | 100nF            | Supply voltage bypass        |                               | Danger of oscillation          |

### TYPICAL CHARACTERISTICS:

Refer to the application circuit of fig.1A  $T_{amb} = 25^{\circ}\text{C}$ ;  $V_S = 20\text{V}$ ;  $R_L = 8\Omega$ ;  $F = 1\text{KHz}$ ;  $R_s = 50\Omega$ ; unless otherwise specified.

**Figure 2:** Output Power vs Supply Voltage



**Figure 3:** Distortion vs Output Power

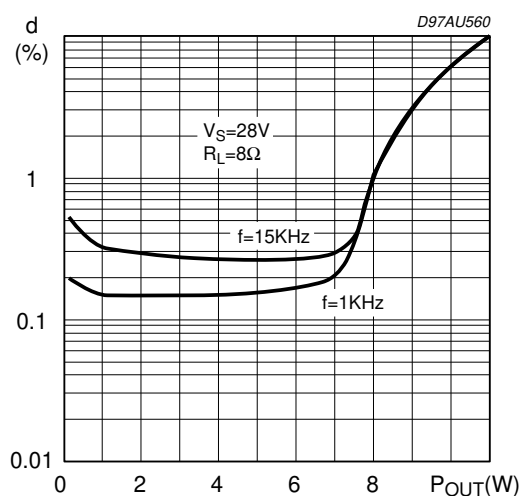


Figure 4: Output Power vs Supply Voltage

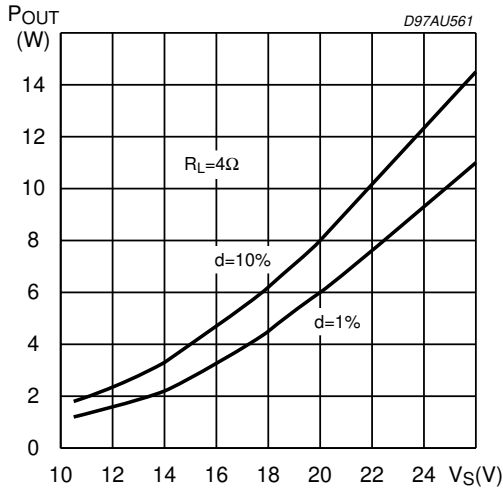


Figure 5: Distortion vs Output Power

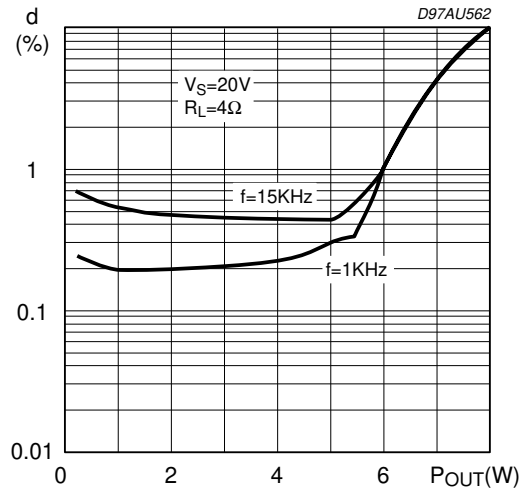


Figure 6: gain vs Volume Control (pin #3)

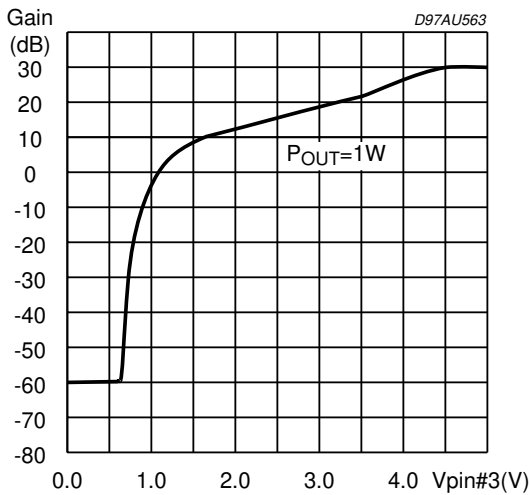


Figure 7: Supply Voltage vs Frequency

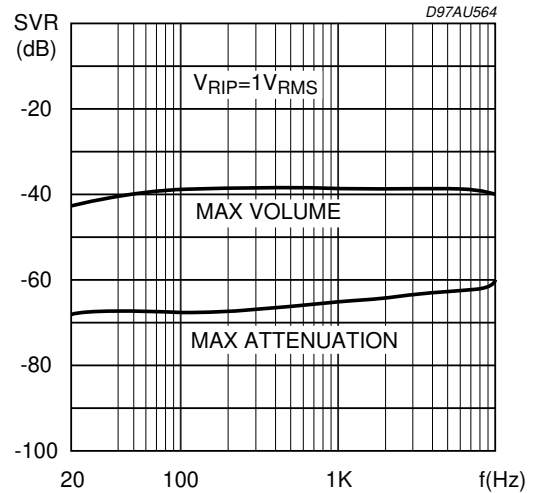


Figure 8: Stand-by Attenuation vs Vpin #9

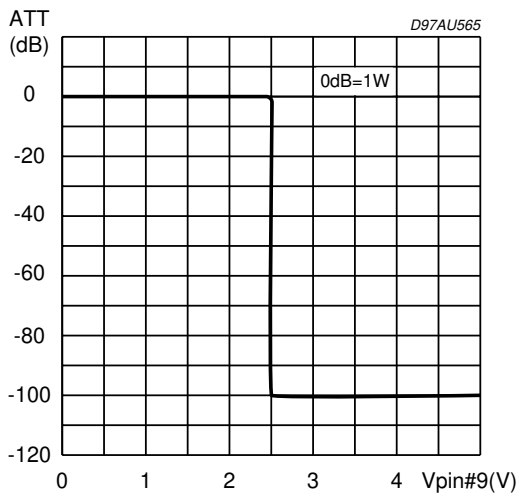


Figure 9: Mute Attenuation vs V pin #10

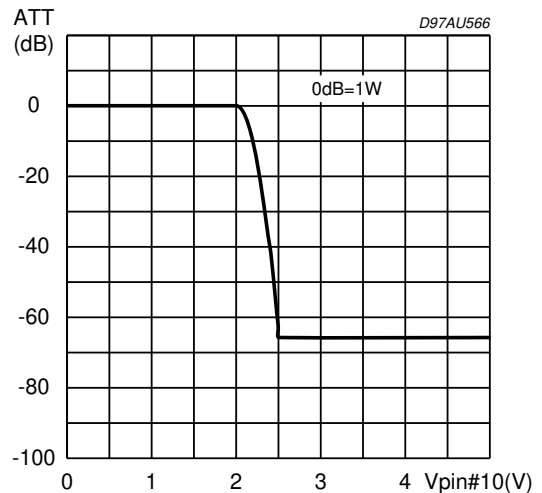


Figure 10: Power dissipation vs Output Power

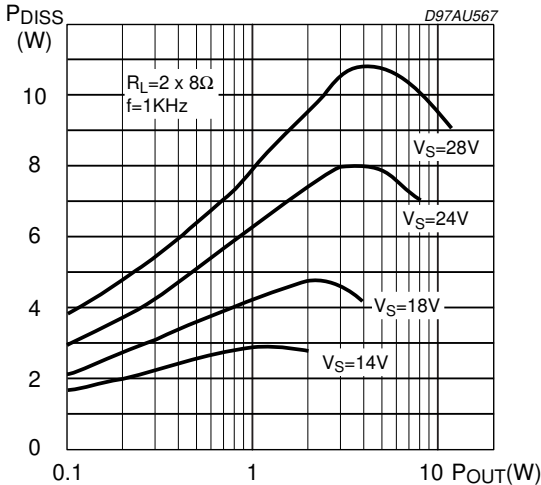
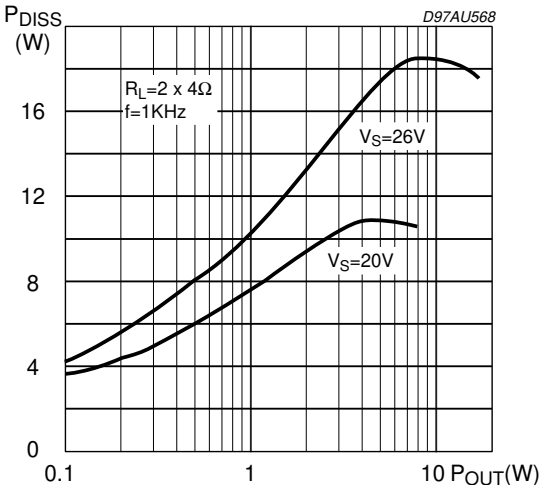


Figure 11: Power Dissipation vs Output Power

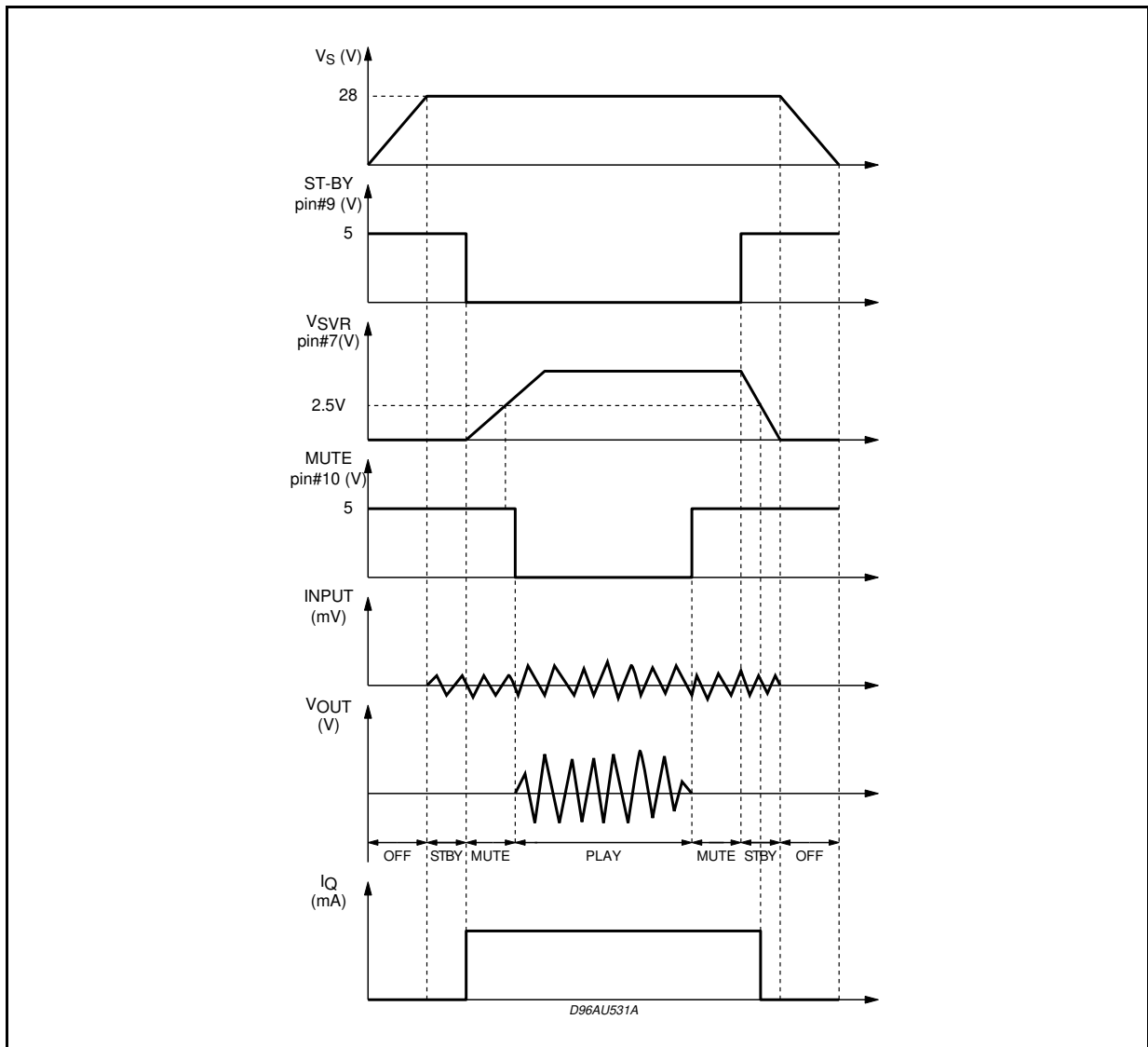


**MUTE STAND-BY TRUTH TABLE**

| MUTE | ST-BY | OPERATING CONDITION |
|------|-------|---------------------|
| H    | H     | STANDBY             |
| L    | H     | STANDBY             |
| H    | L     | MUTE                |
| L    | L     | PLAY                |

**Turn ON/OFF Sequences (for optimizing the POP performances)**

**A) USING MUTE AND STAND-BY FUNCTIONS**



**B) USING ONLY THE MUTE FUNCTION**

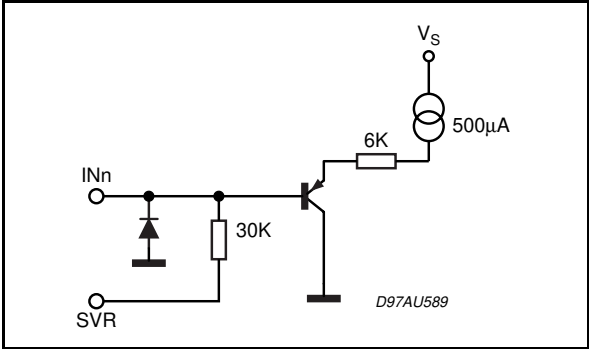
To simplify the application, the stand-by pin can be connected directly to Ground.

During the ON/OFF transitions we recommend to respect the following conditions:

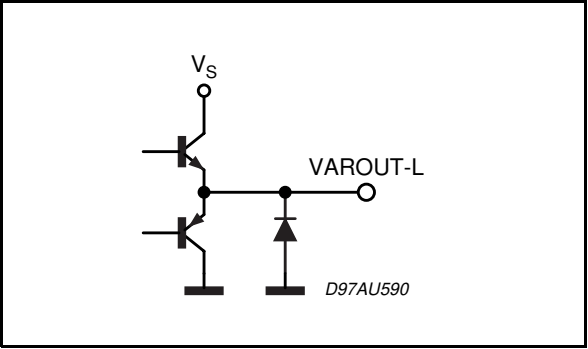
- At the turn-on the transition mute to play must be made when the SVR pin is higher than 2.5V
- At the turn-off the TDA7495 must be brought to mute from the play condition when the SVR pin is higher than 2.5V.



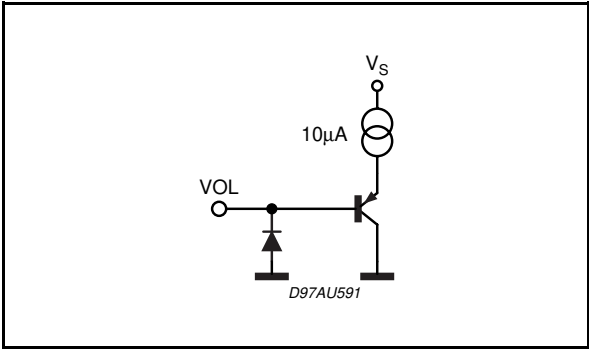
**PINS:** INL, INR



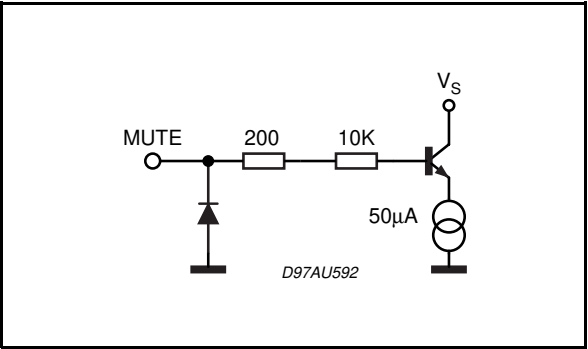
**PINS:** VAROUT-L, VAROUT-R



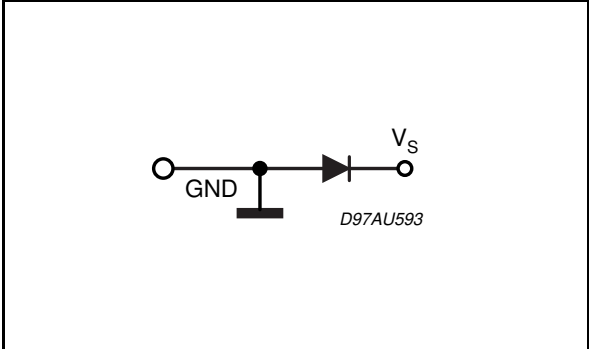
**PIN:** VOLUME



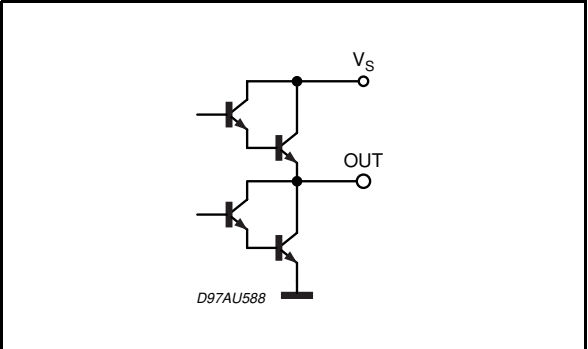
**PIN:** MUTE



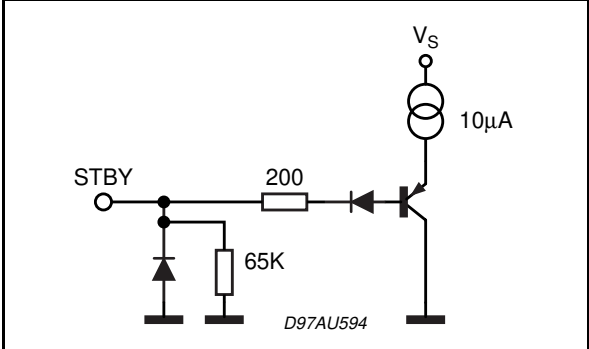
**PINS:** PW-GND, S-GND



**PINS:** OUT R, OUT L

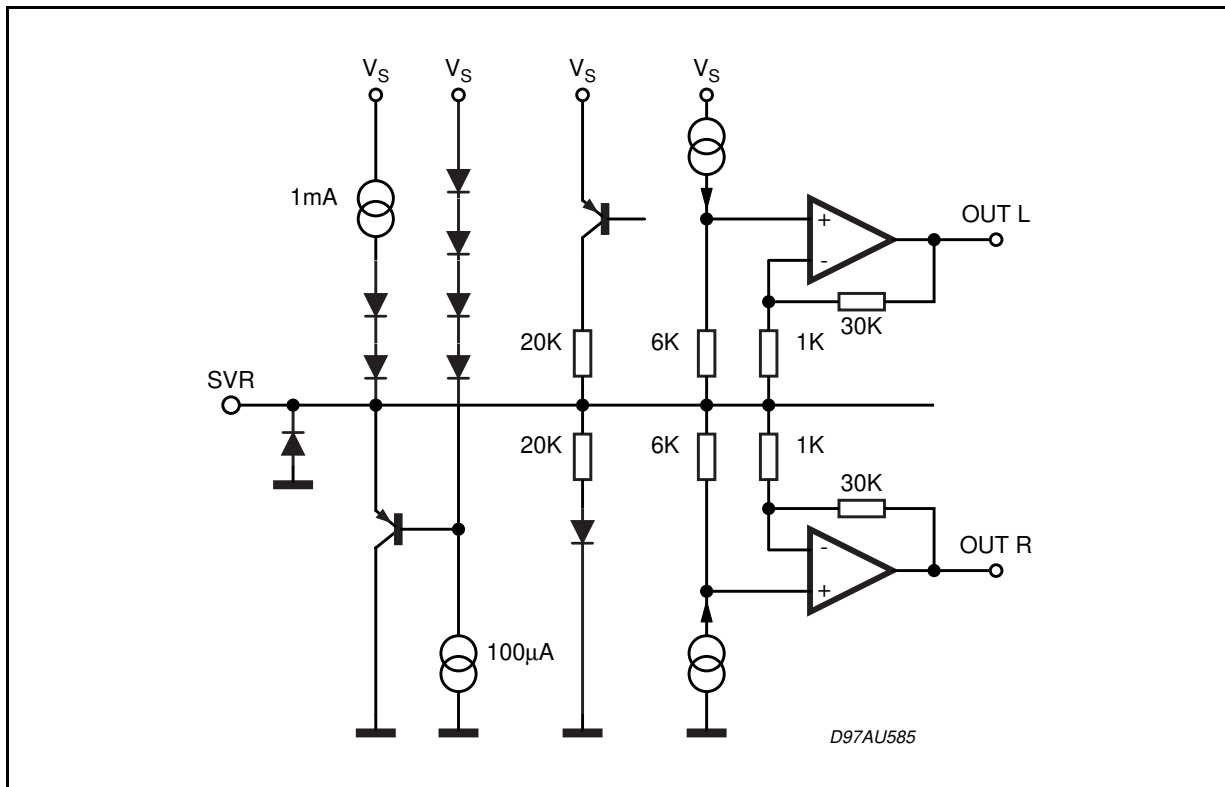


**PIN:** STBY



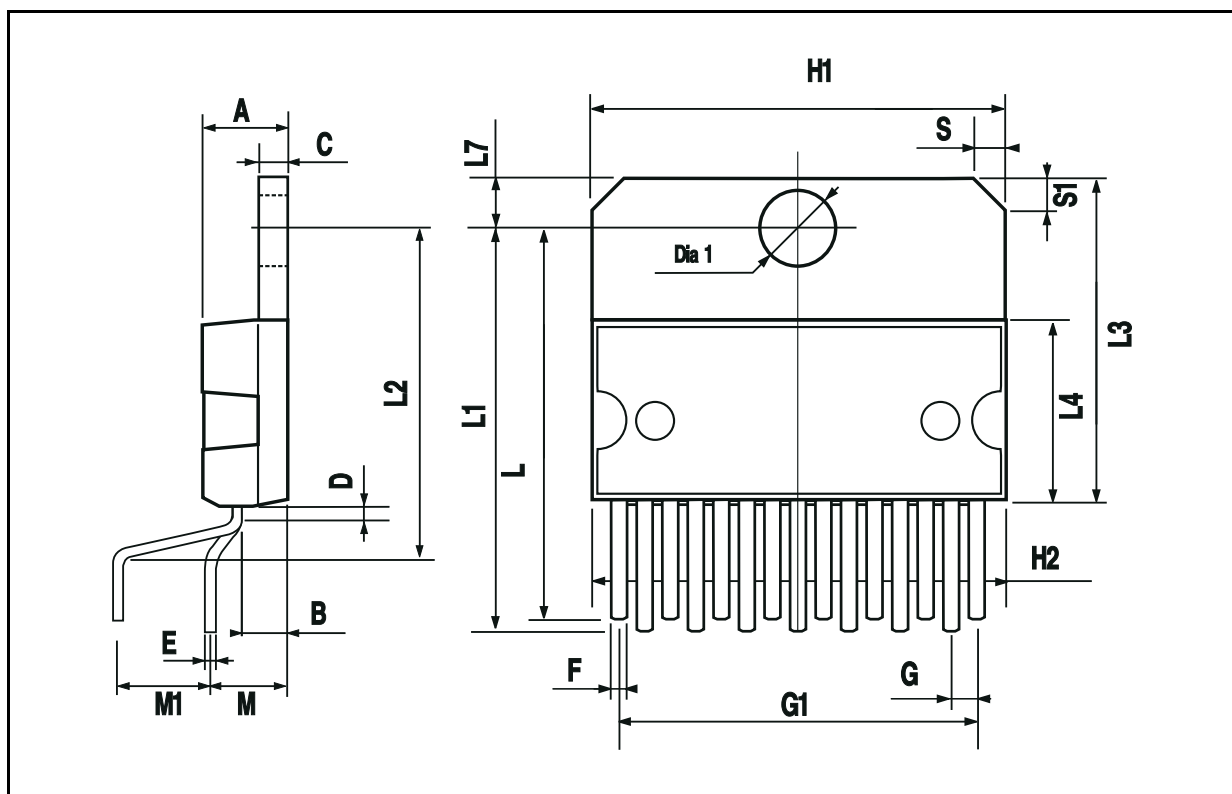
TDA7495

PIN: SVR



## MULTIWATT15 PACKAGE MECHANICAL DATA

| DIM. | mm    |       |       | inch  |       |       |
|------|-------|-------|-------|-------|-------|-------|
|      | MIN.  | TYP.  | MAX.  | MIN.  | TYP.  | MAX.  |
| A    |       |       | 5     |       |       | 0.197 |
| B    |       |       | 2.65  |       |       | 0.104 |
| C    |       |       | 1.6   |       |       | 0.063 |
| D    |       | 1     |       |       | 0.039 |       |
| E    | 0.49  |       | 0.55  | 0.019 |       | 0.022 |
| F    | 0.66  |       | 0.75  | 0.026 |       | 0.030 |
| G    | 1.02  | 1.27  | 1.52  | 0.040 | 0.050 | 0.060 |
| G1   | 17.53 | 17.78 | 18.03 | 0.690 | 0.700 | 0.710 |
| H1   | 19.6  |       |       | 0.772 |       |       |
| H2   |       |       | 20.2  |       |       | 0.795 |
| L    | 21.9  | 22.2  | 22.5  | 0.862 | 0.874 | 0.886 |
| L1   | 21.7  | 22.1  | 22.5  | 0.854 | 0.870 | 0.886 |
| L2   | 17.65 |       | 18.1  | 0.695 |       | 0.713 |
| L3   | 17.25 | 17.5  | 17.75 | 0.679 | 0.689 | 0.699 |
| L4   | 10.3  | 10.7  | 10.9  | 0.406 | 0.421 | 0.429 |
| L7   | 2.65  |       | 2.9   | 0.104 |       | 0.114 |
| M    | 4.25  | 4.55  | 4.85  | 0.167 | 0.179 | 0.191 |
| M1   | 4.63  | 5.08  | 5.53  | 0.182 | 0.200 | 0.218 |
| S    | 1.9   |       | 2.6   | 0.075 |       | 0.102 |
| S1   | 1.9   |       | 2.6   | 0.075 |       | 0.102 |
| Dia1 | 3.65  |       | 3.85  | 0.144 |       | 0.152 |



Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectronics.

© 1997 SGS-THOMSON Microelectronics – Printed in Italy – All Rights Reserved

SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.